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台舟电子

ESD5V0U04-DFN3-A

2-Line Ultra Low Capacitance TVS Diode

www.sot23.com.tw

Features

- Ultra small package: 1.0x0.6x0.5mm
- Ultra low capacitance: 0.4pF typical (I/O-I/O)
- Ultra low leakage: nA level
- Low operating voltage: 5V
- Low clamping voltage
- 3-pin leadless package
- Up to 2-line protects
- Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test
    - Air discharge: ±20kV
    - Contact discharge: ±15kV
  - IEC61000-4-4 (EFT) 40A (5/50ns)
  - IEC61000-4-5 (Lightning) 4A (8/20μs)
- RoHS Compliant

Ordering Information

Part Number	Qty per Reel	Reel Size
ESD5V0U04-DFN3-A	10000	7″

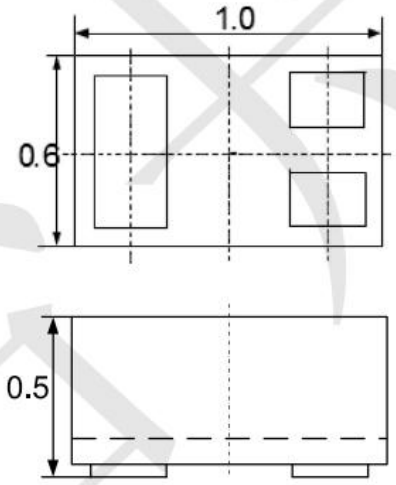
Mechanical Characteristics

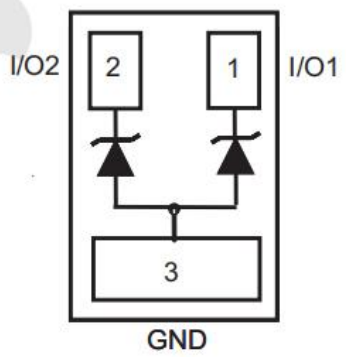
- Package: DFN1006-3 (1.0×0.6×0.5mm)
- Lead Finish: NiPdAu
- Case Material: “Green” Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram Below

Applications

- Cellular Handsets & Accessories
- Digital Visual Interface (DVI)
- Display Port
- MDDI Ports
- USB Ports
- PCI Express
- Serial ATA

Dimensions and Pin Configuration





MARKING: 5*

5= Device code

***= Month code**

Absolute Maximum Ratings (Tamb=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	80	W
Peak Pulse Current (8/20μs)	I_{PP}	4	A
ESD per IEC 61000−4−2 (Air) ESD per IEC 61000−4−2 (Contact)	V_{ESD}	±20 ±15	kV
Operating Temperature Range	T_J	−55 to +125	°C
Storage Temperature Range	Tstg	−55 to +150	°C

Electrical Characteristics (TA=25°C unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Breakdown Voltage	V_{BR}	6.1		7.2	V	I_T = 1mA, pin 1 or pin 2 to pin 3 and between pin 1 and pin 2
Reverse Leakage Current	I_R			0.08	uA	V_{RWM} = 5V, Pin 1 or pin 2 to pin 3 and between pin 1 and pin 2
Clamping Voltage	V_C			12	V	I_{PP} = 1A (8 x 20μs pulse), pin 1 or pin 2 to pin 3
Clamping Voltage	V_C			15	V	I_{PP} = 4A (8 x 20us pulse), pin 1 or pin 2 to pin 3
Junction Capacitance	C_J		0.3		pF	~~VR = 0V, f = 1MHz, between pin 1 and pin 2~~
Junction Capacitance	C_J			0.6	pF	VR = 0V, f = 1MHz, pin 1 or pin 2 to pin 3

Typical Performance Characteristics (T_A=25°C unless otherwise Specified)

Fig1. 8/20μs Pulse Waveform

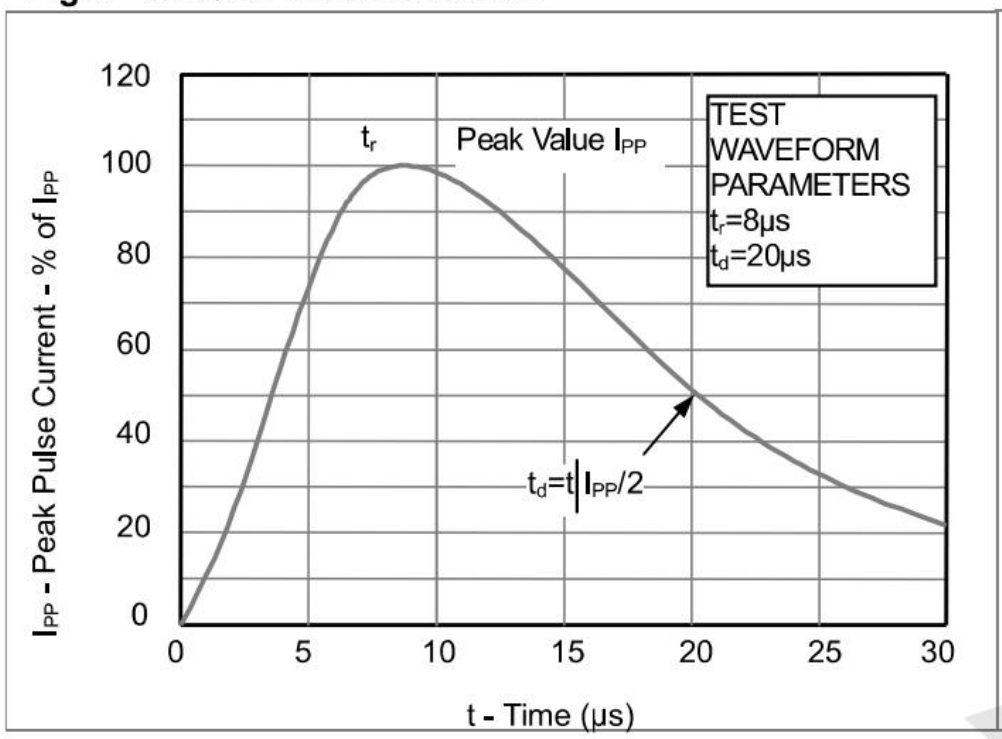


Fig2. ESD Pulse Waveform (according to IEC 61000-4-2)

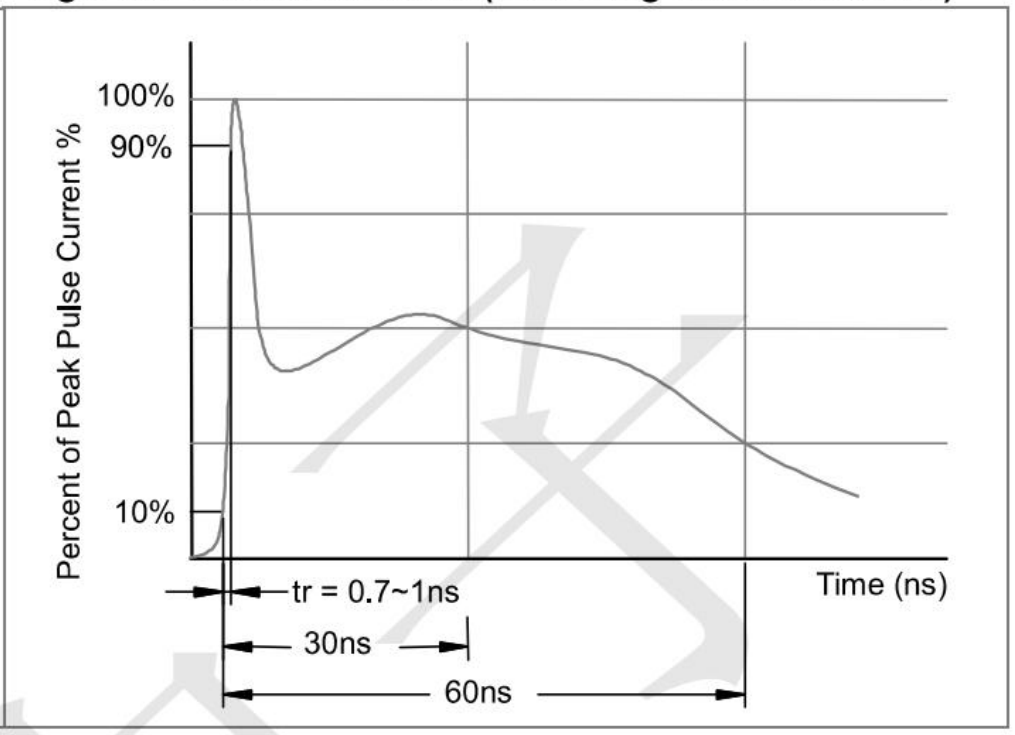
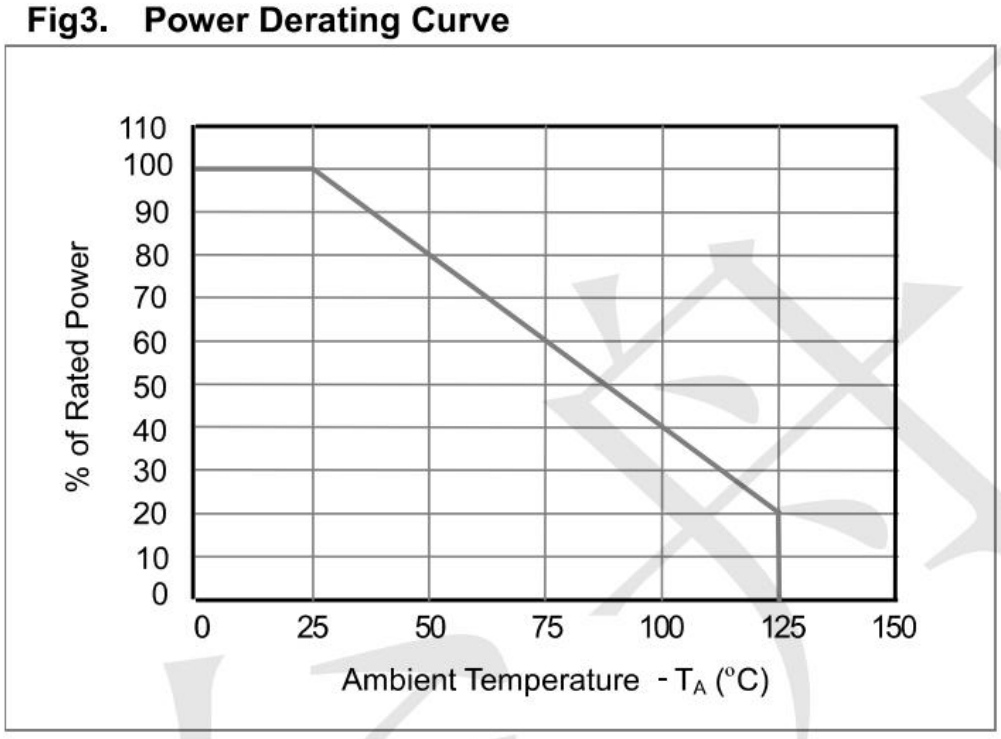
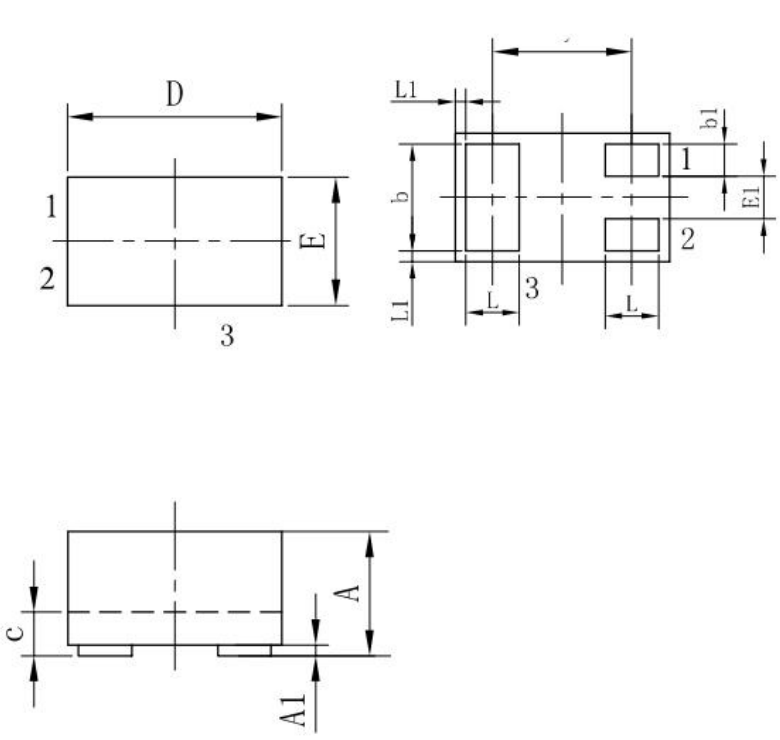


Fig3. Power Derating Curve

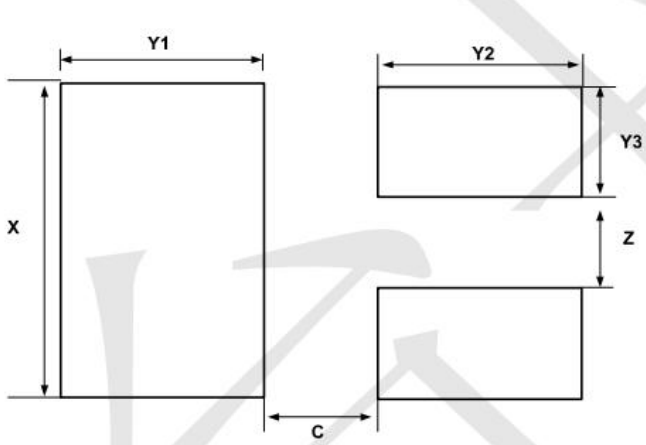


Outline Drawing - DFN1006-3



SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.45	0.50	0.55	0.018	0.020	0.022
b1	0.10	0.15	0.20	0.004	0.006	0.008
c	0.12	0.15	0.18	0.005	0.006	0.007
D	0.95	1.00	1.05	0.037	0.039	0.041
e	0.65 BSC			0.026 BSC		
E	0.55	0.60	0.65	0.022	0.024	0.026
E1	0.15	0.20	0.25	0.006	0.008	0.010
L	0.20	0.25	0.30	0.008	0.010	0.012
L1	0.05 REF			0.0002 REF		

Land Pattern -DFN1006-3



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
C	0.25	0.010
X	0.65	0.024
Y1	0.50	0.020
Y2	0.50	0.020
Y3	0.25	0.010
Z	0.20	0.008